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Attorney Docket Number

U.S. PATENT DOCUMENTS Examiner Cite Document Number Publication Date Pages, Columns, Lines, Where No MM-DD-YYYY Applicant of Cited Relevant Passages or Relevant Initials Number-Kind Code² (if known) Document Figures Appear US-US-US-US-HS.

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		JP 2001-338978	12/07/2001	K. Furusawa, et al.		Α			
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		Japanese Official Action dated May 12, 2009, for Japanese Application No. 2003-317572.			
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		Y. Uchimaru, et al., "Synthesis, Thin Film Formation and Evaluation of a Low-K Silicon-Borazine Polymer", <u>Polymer Preprints</u> , Vol. 51, No. 12 (2002), pp.3077-3078.	Т		
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